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Diodes Incorporated DMN6040SSS-13

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DMN6040SSS

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = 25°C
	40mΩ @ V _{GS} = 10V	5.5A
60V	55mΩ @ V _{GS} = 4.5V	4.7A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

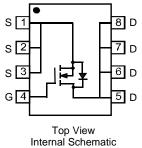
Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)





Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6040SSS-13	SO-8	2500/Tape & Reel

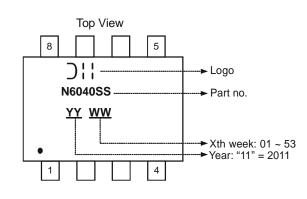
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:







DMN6040SSS

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units
			V _{DSS}	60	V
			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = 25°C T _A = 70°C	Ι _D	5.5 4.4	A
	t<10s	T _A = 25°C T _A = 70°C	۱ _D	7.0 5.5	A
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	2.5	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	30	A
Avalanche Current (Note 7) L = 0.1mH			I _{AR}	14.2	A
Repetitive Avalanche Energy (Note 7) L = 0.1mH			E _{AR}	10	mJ

Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)	T _A = 25°C	P	1.5	W	
Total Power Dissipation (Note 5)	T _A = 70°C	PD	1		
Thermal Registance, Junction to Ambient (Note 5)	Steady State	D	80	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ heta JA}$	48		
Total Dower Dissinction (Note C)	T _A = 25°C		2.0	10/	
Total Power Dissipation (Note 6)	T _A = 70°C	PD	1.3	W	
Thermal Registeres, Junction to Ambient (Note 6)	Steady State	D	61	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ heta JA}$	37		
Thermal Resistance, Junction to Case	$R_{ ext{ heta}JC}$	6.4			
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to 150	°C	

Electrical Characteristics T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)					•		
Drain-Source Breakdown Voltage	BV _{DSS}	60	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			100	nA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(th)}	1	_	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			30	40	mΩ	$V_{GS} = 10V, I_D = 4.5A$	
Static Drain-Source On-Resistance	R _{DS (ON)}		35	55	1115.2	$V_{GS} = 4.5V, I_D = 3.5A$	
Forward Transfer Admittance	Y _{fs}		4.5	_	S	$V_{DS} = 10V, I_D = 4.3A$	
Diode Forward Voltage	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}		1287	_		V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	C _{oss}		57	_	pF		
Reverse Transfer Capacitance	Crss		44	_			
Gate Resistance	R _G		1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = 10V)	Qg		22.4	_			
Total Gate Charge (V _{GS} = 4.5V)	Qg		10.4	_	nC	$V_{DS} = 30V, I_D = 4.3A$	
Gate-Source Charge	Q _{gs}		4.9		no		
Gate-Drain Charge	Q _{gd}		3.0	_			
Turn-On Delay Time	t _{D(on)}		6.6	_			
Turn-On Rise Time	tr		8.1	_	nS	$\label{eq:VGS} \begin{split} V_{GS} = 10V, V_{DD} = 30V, R_G = 6\Omega, \\ I_D = 4.3A \end{split}$	
Turn-Off Delay Time	t _{D(off)}		20.1	_	115		
Turn-Off Fall Time	t _f		4.0	_			
Body Diode Reverse Recovery Time	trr		18	_	nS	I _S = 4.3A, dI/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	11.9	_	nC	I _S = 4.3A, dI/dt = 100A/µs	

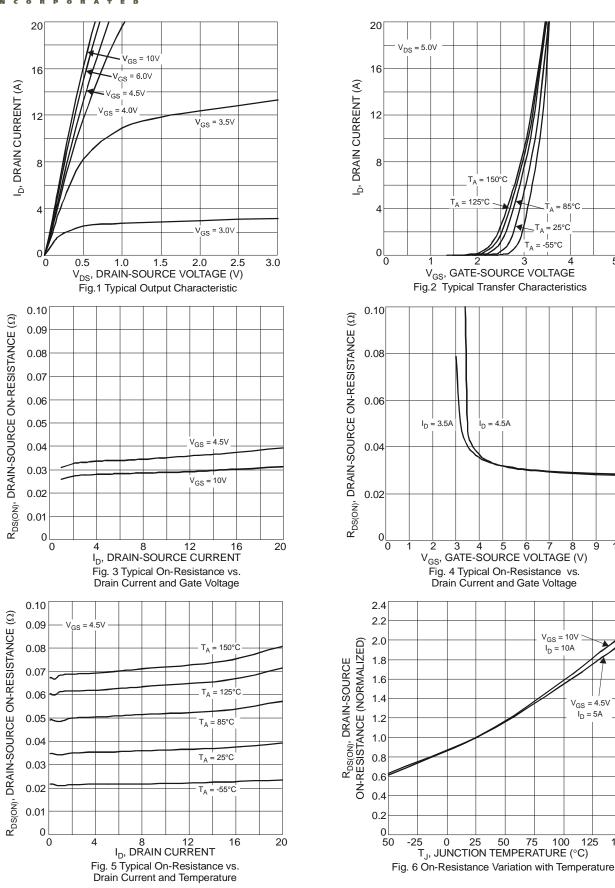
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. J_{AR} and E_{AR} rating are based on low frequency and duty cycles to keep $T_J = 25^{\circ}C$ 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.







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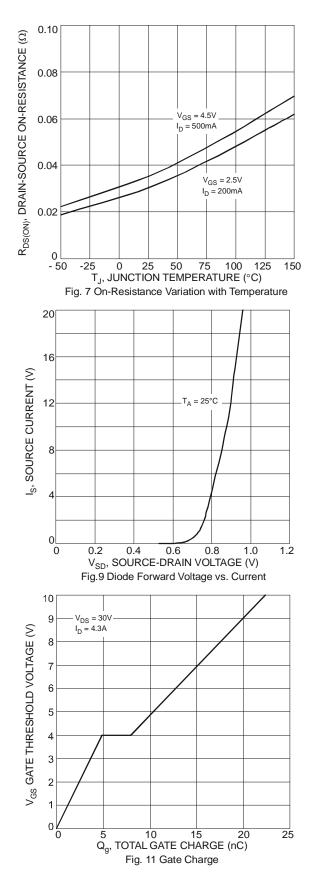
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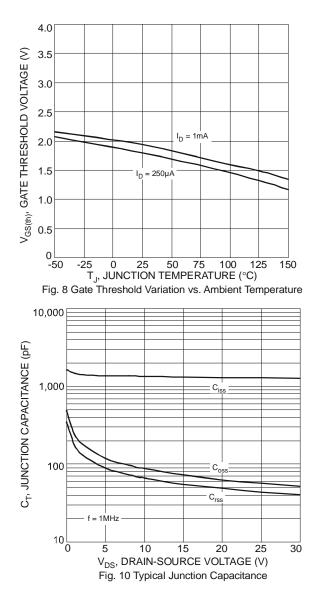
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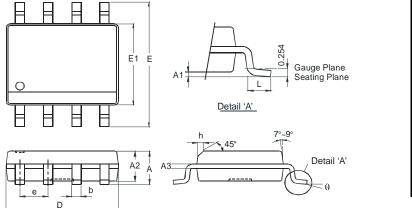
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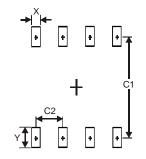
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Package Outline Dimensions



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
Е	5.90	6.10			
E1	3.85	3.95			
e	1.27 Typ				
h	-	0.35			
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27





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